

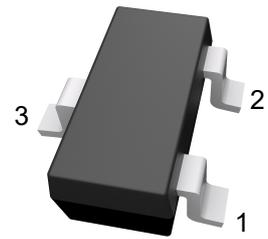
Features

- $V_{DS} = -60V$ $I_D = -4A$
- $R_{DS(ON)} = 180m\Omega(max)$ @-10V
- Halogen and Antimony Free

Applications

- Load Switch and in PWM Applications
- Power Management

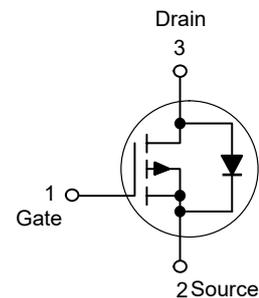
SOT-23-3



1. Gate 2. Source 3. Drain

Marking: Q9

Schematic Diagram



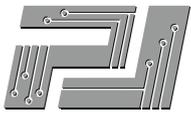
Absolute Maximum Ratings

Ratings at $T_A = 25^\circ C$ unless otherwise specified.

| Parameter | Symbol | Value | Units |
|--|----------------|-----------------|------------|
| Drain-Source Voltage | $-V_{DS}$ | 60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current | $-I_D$ | 4 | A |
| Pulsed Drain Current ^{Note1} | $-I_{DM}$ | 20 | A |
| Power Dissipation | P_D | 1.4 | W |
| Junction and Storage Temperature Range | T_J, T_{STG} | 150, -55 to 150 | $^\circ C$ |

Thermal Characteristics

| Parameter | Symbol | Typ. | Units |
|--|-----------------|------|--------------|
| Maximum Junction-to-Ambient ^{Note2} | $R_{\theta JA}$ | 89 | $^\circ C/W$ |

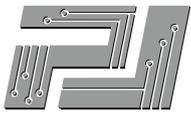


Electrical Characteristics ($T_C=25^\circ\text{C}$ unless otherwise specified)

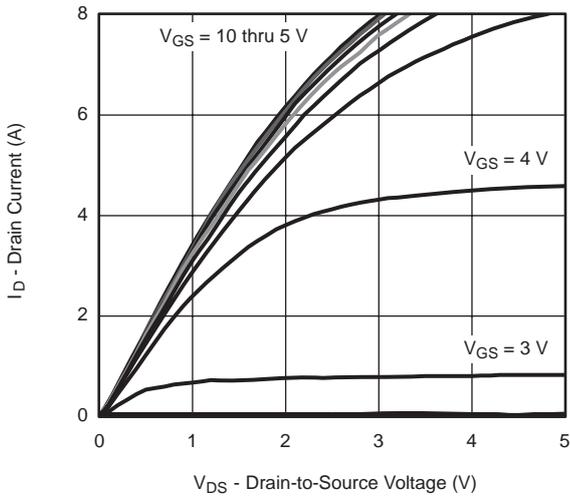
| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Units |
|---|----------------|--|------|------|-----------|------------|
| Static Characteristics | | | | | | |
| Drain-source breakdown voltage | $-V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = -250\mu A$ | 60 | -- | -- | V |
| Drain to Source Leakage Current | $-I_{DSS}$ | $V_{DS} = -60V, V_{GS} = 0V$ | -- | -- | 1 | μA |
| Gate-body leakage current | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | -- | -- | ± 100 | nA |
| Gate threshold voltage ^{Note3} | $-V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = -250\mu A$ | 1.5 | -- | 3 | V |
| Drain-source on-resistance ^{Note3} | $R_{DS(on)}$ | $V_{GS} = -10V, I_D = -2A$ | -- | -- | 180 | m Ω |
| | | $V_{GS} = -4.5V, I_D = -1A$ | -- | -- | 280 | m Ω |
| Forward transconductance ^{Note3} | g_{FS} | $V_{DS} = -5V, I_D = -2A$ | -- | 6 | -- | S |
| Dynamic characteristics | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = -30V, V_{GS} = 0V, f = 1MHz$ | -- | 850 | -- | pF |
| Output Capacitance | C_{oss} | | -- | 65 | -- | |
| Reverse Transfer Capacitance | C_{rss} | | -- | 28 | -- | |
| Switching Characteristics | | | | | | |
| Turn-on delay time | $t_{d(on)}$ | $I_D = -1A, V_{DD} = -30V,$ $V_{GS} = -10V, R_{GEN} = 3\Omega,$ $R_L = 7.5\Omega,$ | -- | 7 | -- | ns |
| Turn-on rise time | t_r | | -- | 3 | -- | |
| Turn-off delay time | $t_{d(off)}$ | | -- | 28 | -- | |
| Turn-off fall time | t_f | | -- | 5.5 | -- | |
| Total gate charge | Q_g | $V_{DD} = -30V, V_{GS} = -10V, I_D = -2A$ | -- | 22 | -- | nC |
| Gate-source charge | Q_{gs} | | -- | 2.5 | -- | |
| Gate-drain charge | Q_{gd} | | -- | 6 | -- | |
| Source-Drain Diode characteristics | | | | | | |
| Diode Forward voltage | $-V_{DS}$ | $V_{GS} = 0V, I_S = -4A$ | -- | -- | 1.2 | V |

Notes:

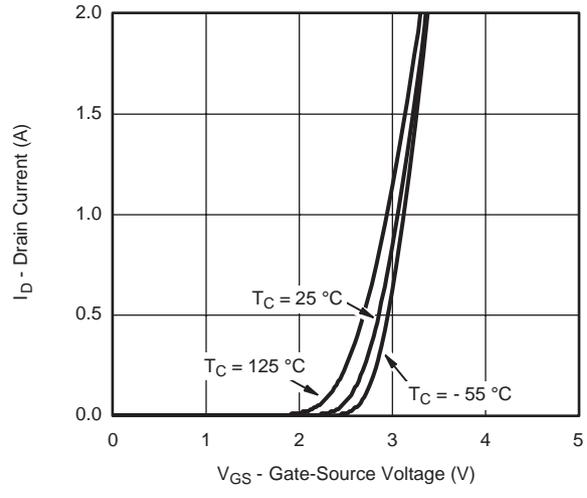
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface mounted on FR4 board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.



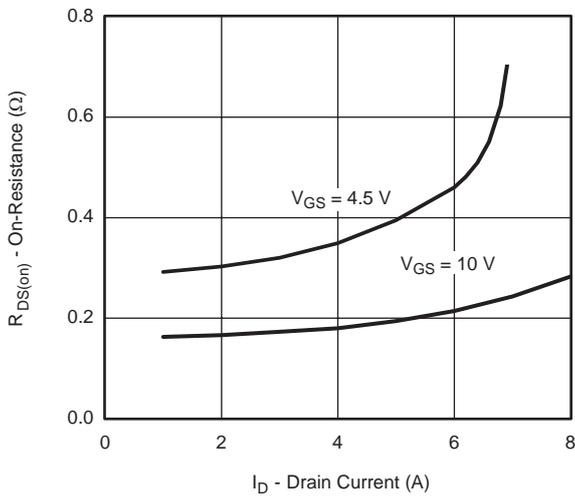
Typical Characteristic Curves



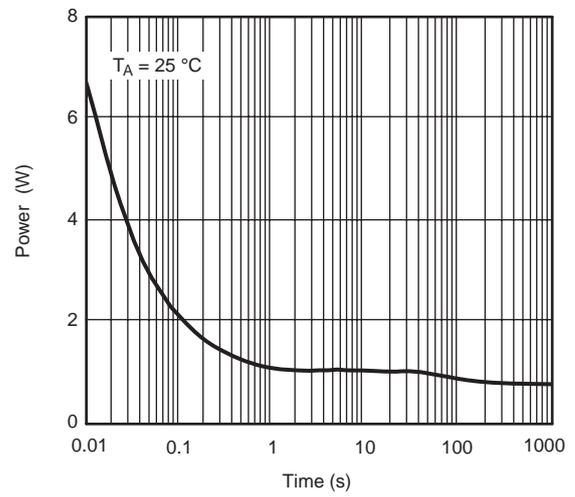
Output Characteristics



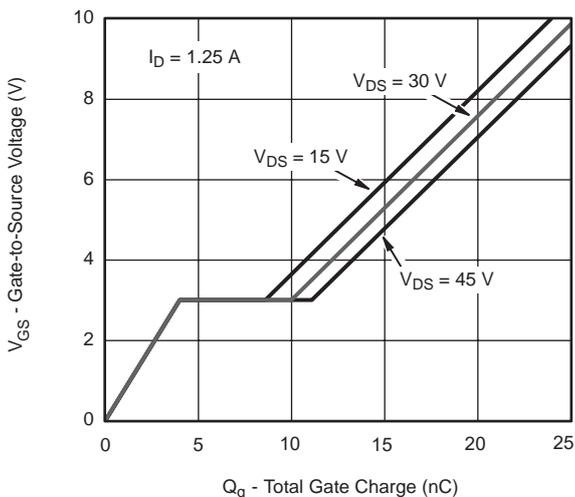
Transfer Characteristics



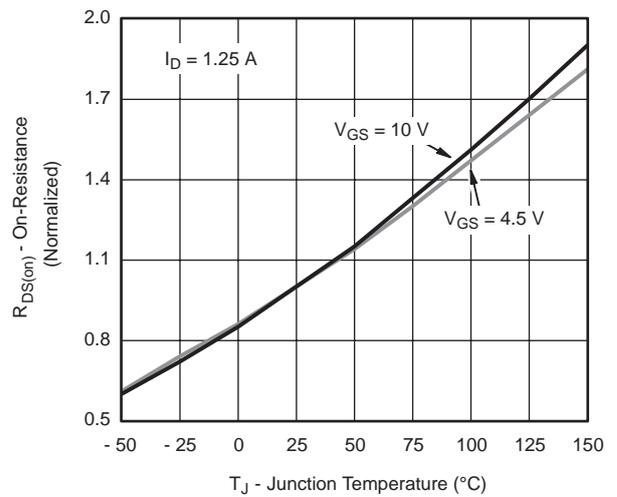
On-Resistance vs. Drain Current and Gate Voltage



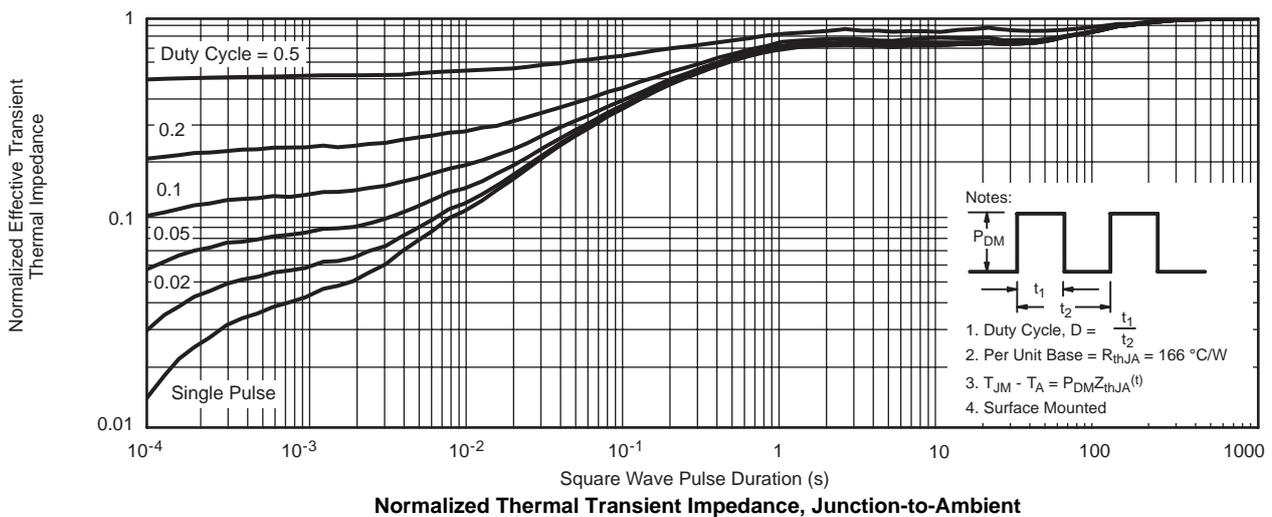
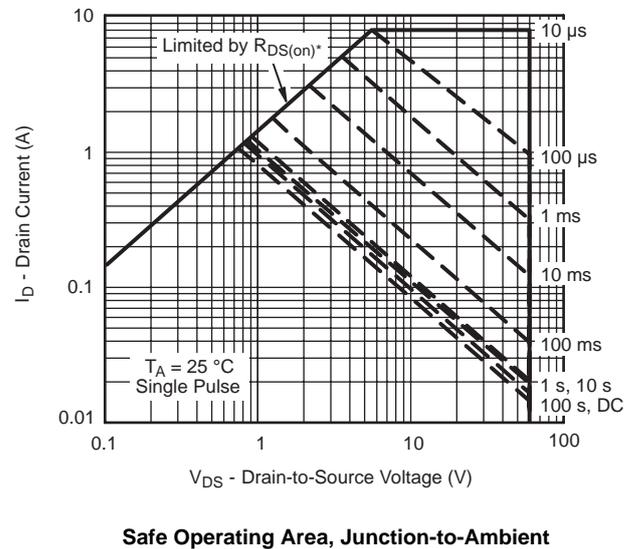
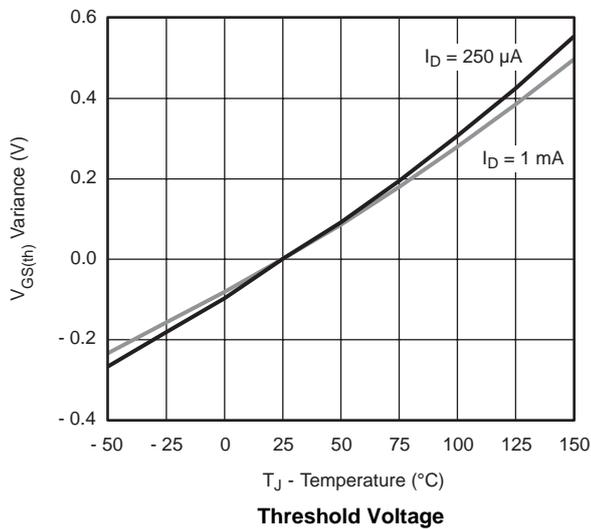
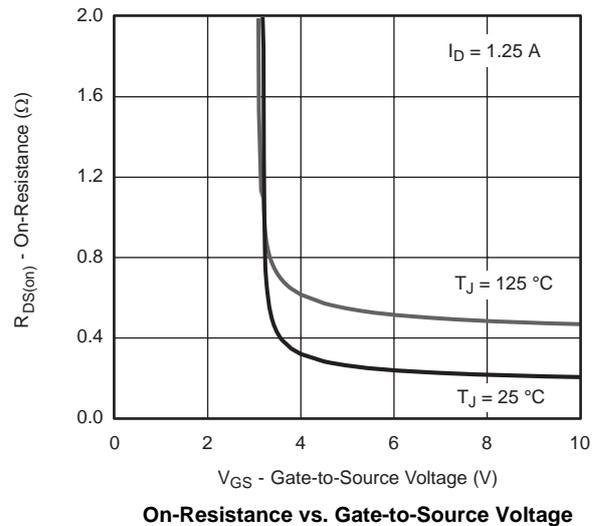
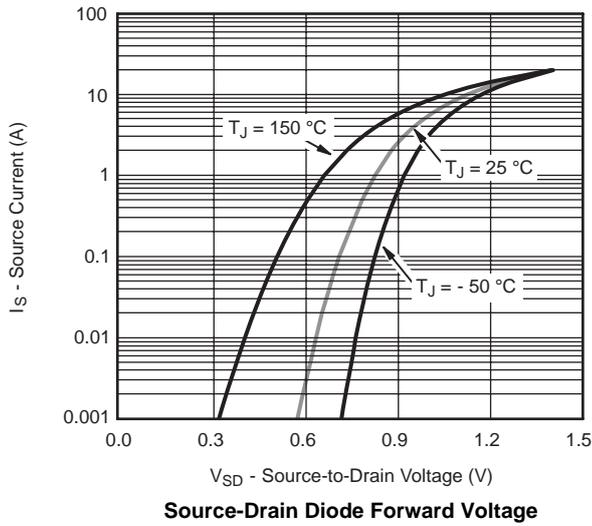
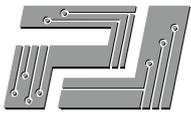
Single Pulse Power, Junction-to-Ambient



Gate Charge



On-Resistance vs. Junction Temperature

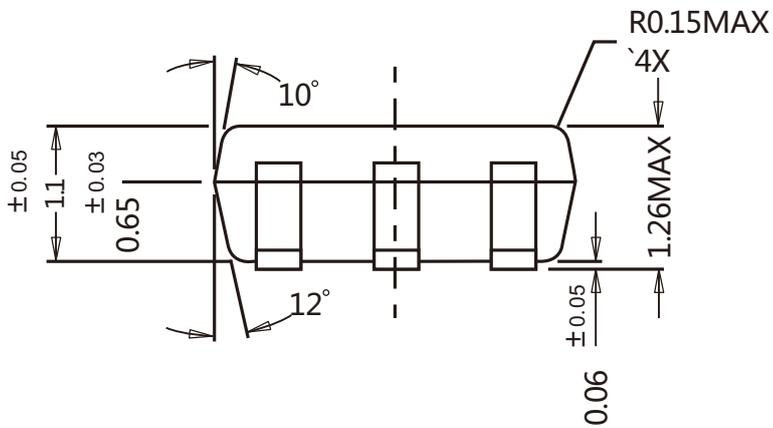
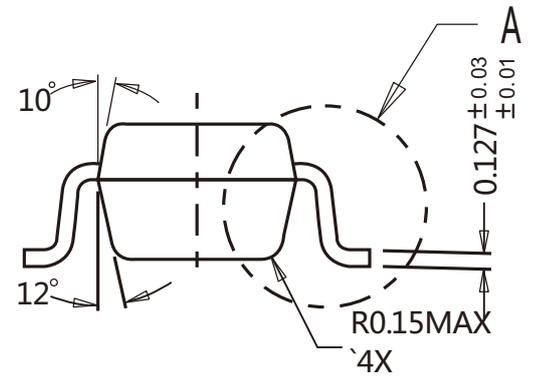
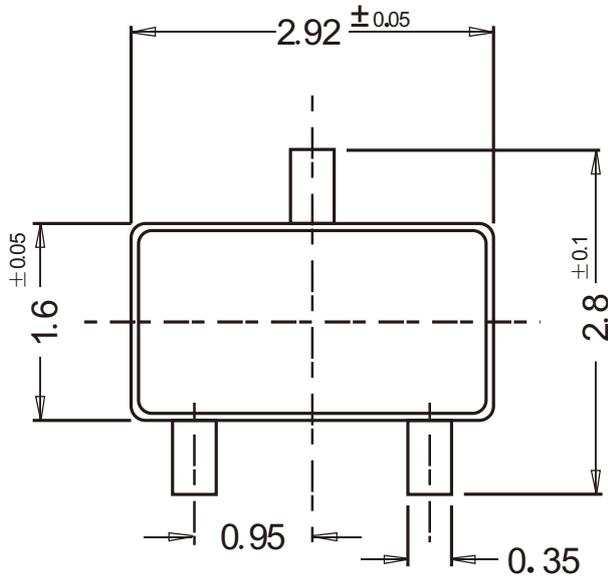




Package Outline

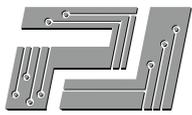
SOT-23-3

Dimensions in mm



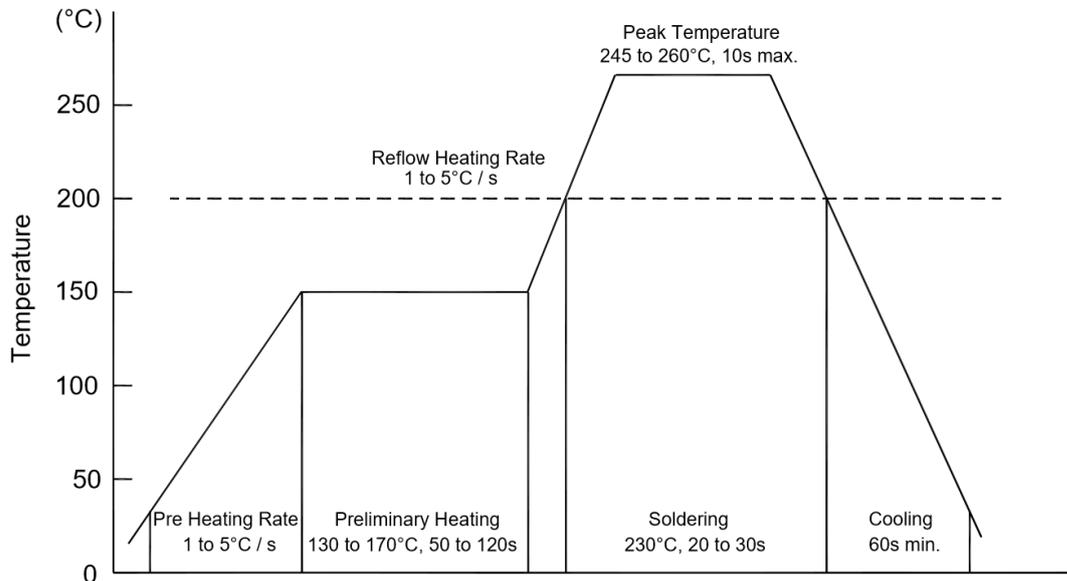
Ordering Information

| Device | Package | Shipping |
|------------|----------|-------------------|
| PJM2309PSC | SOT-23-3 | 3000PCS/Reel&Tape |



Conditions of Soldering And Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

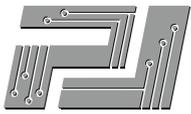
- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

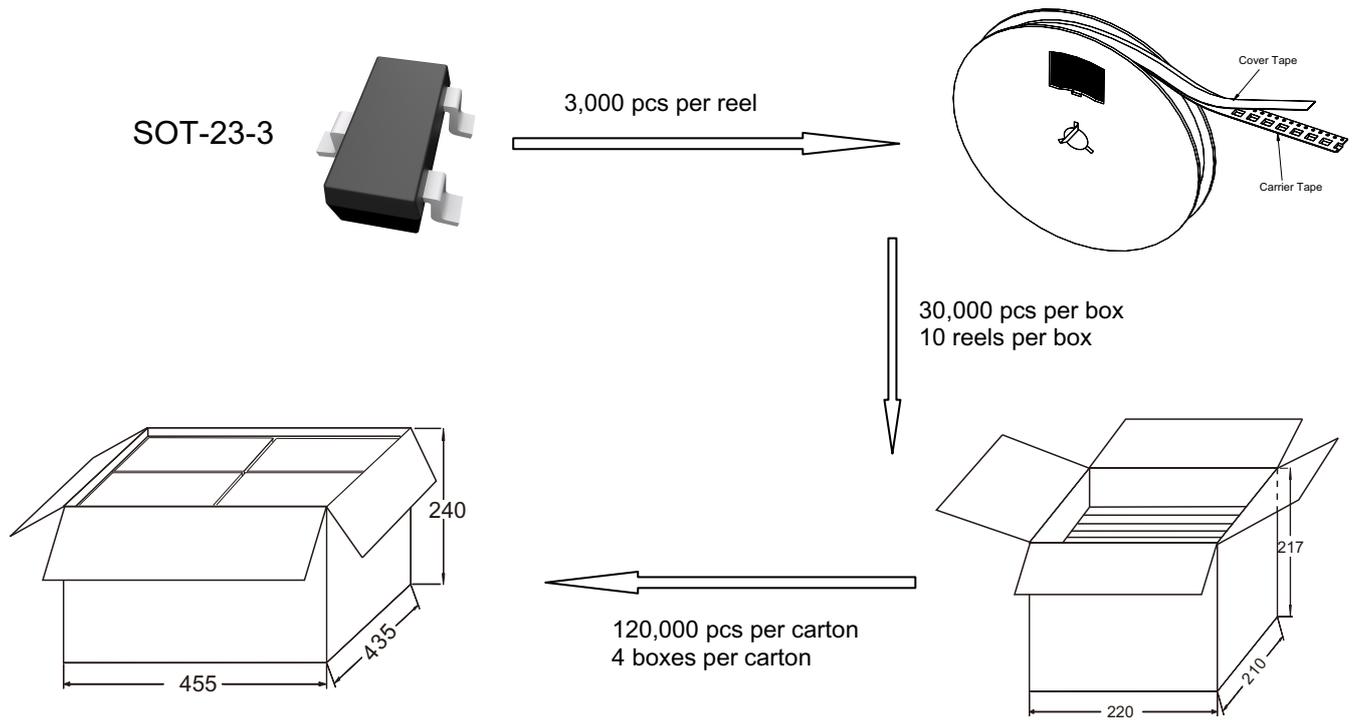
- Temperature: 370 °C
- Time: 3s max.
- Times: one time

◆ Storage conditions

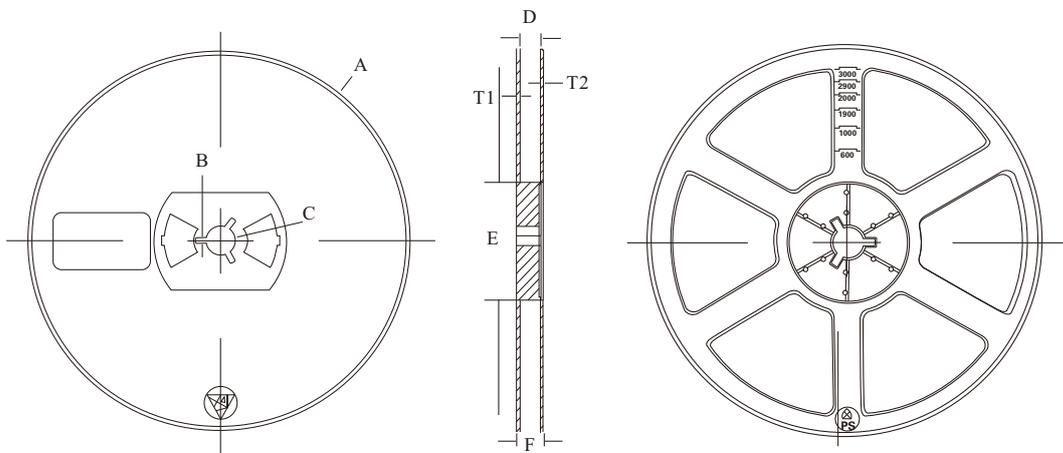
- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing



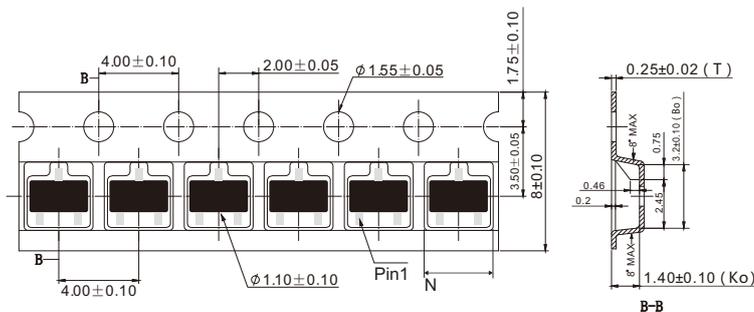
Package Specifications



2. Tape and reel data(7inch Units:mm)



Reel (7")



Tape (8mm)

| Symbol | Value (unit: mm) |
|--------|------------------|
| A | ∅ 177.8±1 |
| B | 2.7±0.2 |
| C | ∅ 13.5±0.2 |
| E | ∅ 54.5±0.2 |
| F | 12.3±0.3 |
| D | 9.6+2/-0.3 |
| T1 | 1.0±0.2 |
| T2 | 1.2±0.2 |
| N | 3.15±0.1 |
| G | 1.22±0.1 |

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